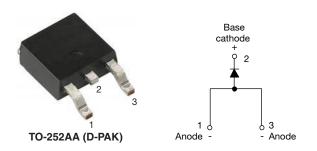


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High Voltage Surface Mountable Input Rectifier Diode, 8 A



PRODUCT SUMMARY						
Package TO-252AA (D-PAK)						
I _{F(AV)}	8 A					
V_{R}	800 V, 1200 V					
V _F at I _F	1.1 V					
I _{FSM}	150 A					
T _J max.	150 °C					
Diode variation	Single die					

FEATURES

- · Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C







HALOGEN

FREE

APPLICATIONS

- · Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-8EWS..S-M3 rectifier high voltage series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

The **high reverse voltage** range available allows design of input stage primary rectification with **outstanding voltage surge** capability.

OUTPUT CURRENT IN TYPICAL APPLICATIONS									
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS									
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 μm) copper	1.2	1.6	_						
Aluminum IMS, R _{thCA} = 15 °C/W	2.5	2.8	А						
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	5.5	6.5							

Note

• $T_A = 55 \,^{\circ}\text{C}$, $T_J = 125 \,^{\circ}\text{C}$, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL CHARACTERISTICS VALUES UNIT									
I _{F(AV)}	Sinusoidal waveform	8	A						
V _{RRM}		800/1200	V						
I _{FSM}		150	A						
V _F	8 A, T _J = 25 °C	1.10	V						
T _J		-55 to +150	°C						

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA					
VS-8EWS08S-M3	800	900	0.5					
VS-8EWS12S-M3	1200	1300	0.5					



VS-8EWS08S-M3, VS-8EWS12S-M3

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ABSOLUTE MAXIMUM RATINGS									
PARAMETER	VALUES	UNITS							
Maximum average forward current	I _{F(AV)}	$T_C = 96$ °C, 180° conduction half sine wave	8						
Maximum peak one cycle	I	10 ms sine pulse, rated V _{RRM} applied	125	Α					
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	150						
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	78	- A ² s					
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	110	A-S					
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A ² √s					

ELECTRICAL SPECIFICATIONS								
PARAMETER	VALUES	UNITS						
Maximum forward voltage drop	V_{FM}	8 A, T _J = 25 °C	1.1	V				
Forward slope resistance	r _t	T _ 150 °C	T 450.00					
Threshold voltage	V _{F(TO)}	1j = 130 C	T _J = 150 °C					
Maximum reverse leakage current		$T_J = 25 ^{\circ}\text{C}$ $V_B = \text{Rated } V_{BBM}$		0.05	mA			
Maximum reverse leakage current	IRM	T _J = 150 °C	VR = nateu VRRM	0.50	IIIA			

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C			
Soldering temperature	T _S		240				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	20.44			
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		62	°C/W			
Approximate weight			1	g			
Approximate weight			0.03	oz.			
Marking daying		Occasional to TO OFFICE A (D. DALK)	8EWS08S				
Marking device		Case style TO-252AA (D-PAK)	8EWS12S				

Note

⁽¹⁾ When mounted on 1 " square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994



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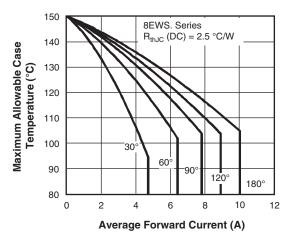


Fig. 1 - Current Rating Characteristics

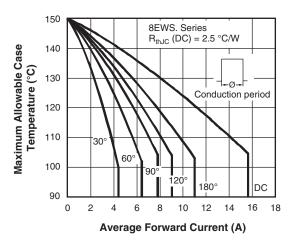


Fig. 2 - Current Rating Characteristics

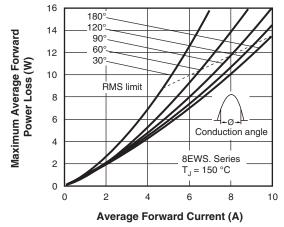


Fig. 3 - Forward Power Loss Characteristics

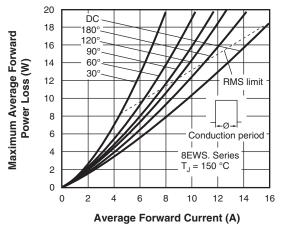
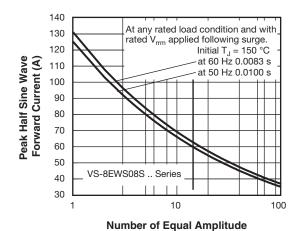


Fig. 4 - Forward Power Loss Characteristics



Half Cycle Current Pulses (N)
Fig. 5 - Maximum Non-Repetitive Surge Current

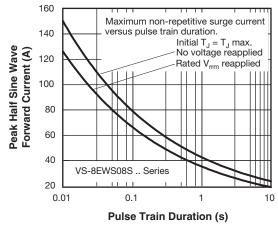


Fig. 6 - Maximum Non-Repetitive Surge Current

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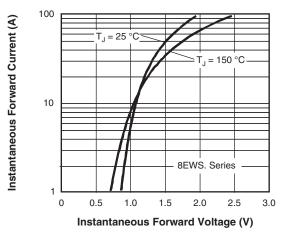


Fig. 7 - Forward Voltage Drop Characteristics

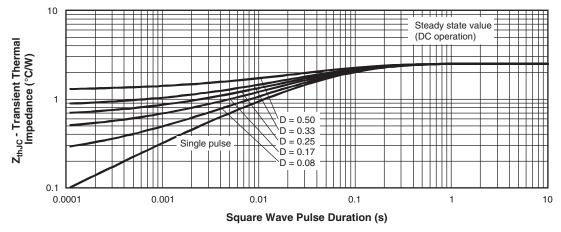
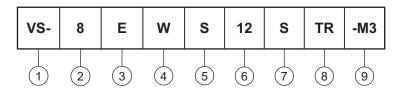


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- Current rating (8 = 8 A)

- Circuit configuration:

E = single diode

4 - Package:

W = D-PAK

5 - Type of silicon:

S = standard recovery rectifier

- Voltage code x 100 = V_{RRM} — 08 = 800 V 12 = 1200 V

7 - S = surface mountable

8 - • TR = tape and reel

• TRR = tape and reel (right oriented)

• TRL = tape and reel (left oriented)

9 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-8EWS08S-M3	75	3000	Antistatic plastic tubes						
VS-8EWS08STR-M3	2000	2000	13" diameter reel						
VS-8EWS08STRL-M3	3000	3000	13" diameter reel						
VS-8EWS08STRR-M3	3000	3000	13" diameter reel						
VS-8EWS12S-M3	75	3000	Antistatic plastic tubes						
VS-8EWS12STR-M3	2000	2000	13" diameter reel						
VS-8EWS12STRL-M3	3000	3000	13" diameter reel						
VS-8EWS12STRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95016</u>					
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				



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INCHES

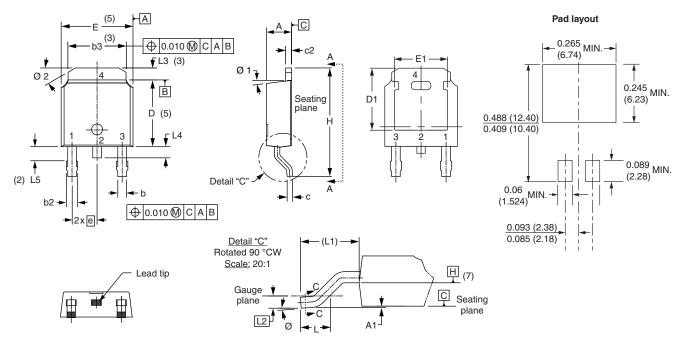
MIN.

MAX.

NOTES

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES		SYMBOL	MILLIMETERS		
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDOL	MIN.	MAX.	
Α	2.18	2.39	0.086	0.094			е	2.29	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	
c2	0.46	0.89	0.018	0.035			L4	-	1.02	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	
D1	5.21	-	0.205	-	3		Ø	0°	10°	
Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	

е	2.29	2.29 BSC		BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74	BSC	0.108	REF.	
L2	0.51	BSC	0.020	BSC	
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	·
Ø2	25°	35°	25°	35°	·
	H L1 L2 L3 L4 L5 Ø	H 9.40 L 1.40 L1 2.74 L2 0.51 L3 0.89 L4 - L5 1.14 Ø 0° Ø1 0°	H 9.40 10.41 L 1.40 1.78 L1 2.74 BSC L2 0.51 BSC L3 0.89 1.27 L4 - 1.02 L5 1.14 1.52 Ø 0° 10° Ø1 0° 15°	H 9.40 10.41 0.370 L 1.40 1.78 0.055 L1 2.74 BSC 0.108 L2 0.51 BSC 0.020 L3 0.89 1.27 0.035 L4 - 1.02 - L5 1.14 1.52 0.045 Ø 0° 10° 0° Ø1 0° 15° 0°	H 9.40 10.41 0.370 0.410 L 1.40 1.78 0.055 0.070 L1 2.74 BSC 0.108 REF. L2 0.51 BSC 0.020 BSC L3 0.89 1.27 0.035 0.050 L4 - 1.02 - 0.040 L5 1.14 1.52 0.045 0.060 Ø 0° 10° 0° 10° Ø1 0° 15° 0° 15°

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- Outline conforms to JEDEC outline TO-252AA



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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